Lithium-Ion Secondary Battery Charge Control IC for AC Charger Monolithic IC MM3324

Outline

This charge control IC has characteristics to monitor battery temperature to control the charge current and charge voltage, and it is in compliance with the Safety Standard that will be put in force in 2011. In addition, this IC has achieved high cost performance in that it has integrated with charge FET and current sensing resistor, which are the external devices in the conventional charge control ICs, and that the reverse current protection function is added.

Features

- Integrated battery temperature monitor and battery control functions in advance preparation for the Safety Standard slated to be effective in 2011.
 Safety of the battery is secured by changing the full charge voltage and charge current when the battery temperature is low and high.
- 2. Can reduce parts and its installation costs thanks to the integrated charging FET and current sensing resistor.
- Because of the control function integrated in the primary side, it is also possible to charge the battery highly efficiently by tracking the battery voltage in addition to the charge control.
 Furthermore, the heat dissipation is minimized.

Package

TSOP-16D



AC Charger

Block Diagram



Pin Assignment



1	CFB1	9	VDD
2	CFB2	10	NC
3	TP1	11	GND
4	CNT	12	TDET
5	TP2	13	Vref
6	PROG	14	CE
7	TP3	15	LED-R
8	BAT	16	LED-G

Pin Description

Pin no.	pin name	I/O	Function	Internal equivalent circuit
1	CFB1	Input	Rated BAT voltage control phase compensation pin. Oscillation is improved by connecting an external capacitor between CFB1 and CNT for phase compensation.	CFB1 CFB1 GND
2	CFB2	Input	Rated V _{DD} voltage control phase compensation pin. Oscillation is improved by connecting an external capacitor between CFB2 and CNT for phase compensation.	CFB2 GND
3	TP1	Input	Terminal 1 for test It is a terminal for the timer test. Please connect it with the opening when you use it usually.	TP1 GND
4	CNT	Output	Photo diode drive pin of photo coupler for VDD and BAT constant voltage and constant current control. Connect to cathode of diode.	
5	TP2	Input	Terminal 2 for test It is a terminal for the timer test. Please connect it with the opening when you use it usually.	TP2 GND
6	PROG	Input	It can adjust the charge current for DC input(VDD) with the value of an external resistor. If setting this value smaller, the charge current can be larger.	PROG GND
7	TP3	Input	Terminal 3 for test It is a terminal for the timer test. Please connect it with the opening when you use it usually.	TP3 GND

Pin no.	pin name	I/O	Function	Internal equivalent circuit
8	BAT	Input	Battery voltage output pin.	Vdd
			Detect battery voltage and control charging.	_
				BAT
				± €
				GND
9	VDD	Input	Power supply input pin.	
10	NC		NC	
11	GND	Input	Ground pin.	
12	TDET	Input	Temperature detection input pin.	VDD
			Apply potential resistance divided by external	Ă
			resistor and thermistor from reference	
			voltage when using.	
			Reset state will exist if TDET pin does not	\downarrow \downarrow \downarrow \downarrow \downarrow
			reach the specified potential.	
				GND
13	VREF	Output	Reference power supply output pin.	
			Outputs about 2.5Volts typ. reference voltage.	
			osed for temperature detection reference	
			power suppry.	VREF
				GND
14	CE	Input	Chip enable pin. (active High)	
				GND
15	LED D	Output	LED Boutput cin	
15	LED-K	Output	LED-K ouiput pin. NMOS-Tr open drain output	LED-R
			Ninos-11 open uran output.	
10	LED C	O ₁ , a ¹ , a ² , b ²	LED Constants a	
16	LED-G	Output	LED-G output pm. NMOS-Tr open drain output	LED-G
			Thirds II open urani output.	
				UND

Absolute Maximum Ratings (Except where noted otherwise Ta=25°C)

Item		Symbol Ratings		Units
Storage temperature		Tstg	-55~+150	°C
Operating temperature		Topr	-40~+85	°C
Supply voltage		VDDMAX	-0.3~+6	V
Power dissipation	IC unit	Pd1	0.3	337
Power dissipation	Substrate mounting (*1)	Pd2	0.8	vv

*1 Boardsize : 50×50×1mm Material : Paper phenolic Layer : Single side Wire rate : 70%

Recommended Operating Conditions

Item	Symbol	Ratings	Units	
Operating temperature	Topr	-40~+75	°C	
Supply voltage	Vopr	2.7~5.9	V	

Electrical Characteristics (Except where noted otherwise Ta=-0~45°C, Vcc=5V)

Item	Symbol	Measurement Conditions	Min.	Тур.	Max.	Unit.
Consumption current	Idd			1	2	mA
Reference voltage	VREF			2.5		V
VDD detection voltage L	VDDL	V _{DD} =H→L	2.35	2.45	2.55	V
VDD detection voltage L hysteresis voltage width (*1)	Vddlw		50	100	150	mV
VDD detection voltage H	Vddh	$V_{DD}=L \rightarrow H$	5.50	5.70	5.90	V
VDD detection voltage H hysteresis voltage width (*1)	Vddhw		50	100	150	mV
VDD control voltage	V _{DD}		4.4	4.5	4.6	V
BAT pin leakage current	Ibat				4	μA
BAT pin output voltage	VBAT1	$VT_2 < T_{DET} \leq VT_5$	4.170	4.200	4.230	V
(VBAT1>VBAT2)	VBAT2	$VT_5 < T_{DET} \leq VT_6$	4.000	4.050	4.100	
Pre-charge current range	IPRECHG	Vlv≤BAT <vp Iprechg=Kp×(Vprechg/Rprog)</vp 	30		85	mA
Fast charge current range	IFSTCHG1	V _P ≤BAT <v<sub>BAT, VT₂<t<sub>DET≤VT₃ IFSTCHG1=K_P×(VFSTCHG1/RPROG)</t<sub></v<sub>	225		640	
	IFSTCHG2	VP≤BAT <vbat,vt3<tdet≤vt6 IFSTCHG2=KP×(VFSTCHG2/RPROG)</vbat,vt3<tdet≤vt6 	300		850	IIIA
Pre-charge PROG pin output voltage	VPRECHG	$V_{LV} \leq BAT < V_P$		0.20		V
	VFSTCHG1	$V_{P} \leq BAT < V_{BAT}, VT_{2} < T_{DET} \leq VT_{3}$		1.50		V
rasi unarge rhod output voltage	VFSTCHG2	$V_P \leq BAT < V_{BAT}, VT_3 < T_{DET} \leq VT_6$	2.0	2.00		v
Charge Current set coefficient KP	Kp			500		
Full charge PROG output voltage	VDETFULL			0.2		V

Note : *1 guaranteed by design

Item	Symbol	Measurement Conditions	Min.	Тур.	Max.	Unit.
Pre-charge current accuracy	APRECHG	IPRECHG=55mA	-35		+35	%
Fast charge current	AFETCHC	VT2 <tdet≦vt3 Ifstchg1=410mA</tdet≦vt3 	-15		+15	- %
accuracy	Tusteno	$VT_3 < T_{DET} \leq VT_6$ IFSTCHG2=550mA	-10		+10	
Detect full charge current accuracy	ADETFULL		-35		+35	%
Low voltage detection voltage	VLV	BAT=L→H	1.90	2.00	2.10	V
Low voltage detection voltage hysteresis voltage width (*1)	VLVW		25	50	100	mV
Pre-charge detection voltage	VP	BAT=L→H	2.80	2.90	3.00	V
Pre-charge detection voltage hysteresis voltage width (*1)	\mathbf{V}_{PW}		25	50	100	mV
Re-charge detection voltage	VR	BAT=H→L	3.85	3.90	3.95	V
Overvoltage detection voltage	Vov	BAT=L→H	4.30	4.35	4.40	V
	V _{T1}	$T_{DET}=L \rightarrow H$	VREF	VREF	V _{REF} ×0.971	v
	• 11	-30°C±6°C detection	×0.937	×0.957		
	V _{T2}	$T_{DET}=L \rightarrow H$	VREF	VREF VREF 0.762 ×0.781	VREF ×0.800	v
Battery Temperature detection TDET pin voltage	• 12	0°C±2°C detection	×0.762			
	V _{T3}	$T_{DET}=L \rightarrow H$	VREF	VREF	VREF	v
		10°C±2.5°C detection	×0.649	×0.677	×0.705	
	V _{T4}	$T_{DET}=H\rightarrow L$ 40°C±2.5°C detection	V _{REF} ×0.313	V _{REF} ×0.336	V _{REF} ×0.361	V
	V _{T5}	$T_{DET}=H\rightarrow L$ $45^{\circ}C\pm 2.5^{\circ}C \text{ detection}$	V _{REF} ×0.269	V _{REF} ×0.290	V _{REF} ×0.313	V
	V _{T6}	$T_{DET}=H\rightarrow L$ 60°C±2.5°C detection	V _{REF} ×0.168	V _{REF} ×0.182	V _{REF} ×0.197	v
	VT7	$T_{DET}=H\rightarrow L$ 80°C±6°C detection	V _{REF} ×0.079	V _{REF} ×0.096	V _{REF} ×0.116	V
Battery Temperature detection T _{DET} pin voltage hysteresis voltage width (*1)	VTHW	VT2, VT3, VT4, VT5, VT6	2	5	8	°C
LED-R pin output voltage	VLED-R	ILED-R=10mA			0.4	V
LED-G pin output voltage	VLED-G	ILED-G=10mA			0.4	V
CNT pin output voltage	VCONT	Icont=5mA			0.4	V
Output transistor ON resistance	Ron	V _{DD} =4.2V		0.35		Ω
First time charge timer	T1STCHG		119.6	149.5	179.4	s
Pre-charge timer	TPRECHG		959	1199	1439	s
Fast charge timer	TFSTCHG		15354	19193	23032	s
Full charge detection delay time	TDETFULL		0.469	0.586	0.703	s
Overvoltage detection delay time	Tov		0.058	0.073	0.088	s
Re-charge detection delay time	TR		0.058	0.073	0.088	S

Note : *1 guaranteed by design

Any products mentioned in this catalog are subject to any modification in their appearance and others for improvements without prior notification.
 The details listed here are not a guarantee of the individual products at the time of ordering. When using the products, you will be asked to check their specifications.

Item	Symbol	Measurement Conditions	Min.	Тур.	Max.	Unit.
First time voltage detection delay time	Tetv		0.117	0.146	0.175	s
LED-R blinking cycle	TBL1	Charge stop VT1 <tdet≦vt2, th="" vt6<tdet≦vt7<=""><th>1.874</th><th>2.342</th><th>2.810</th><th>s</th></tdet≦vt2,>	1.874	2.342	2.810	s
	TBL2	Abnormal charge prohibition	0.937	1.171	1.405	
CE Low-Level input voltage	VCEL	Charge OFF threshold	0		0.3	V
CE High-Level input voltage	VCEH	Charge ON threshold	2		VDD	V
CE pin input current	ICE			10	20	μA

Note : * If the IC is damaged and control is no longer possible, its safety can not be guaranteed. Please protect with something other than this IC.

- Temperature detection is the setting value at B-Value 4250K (25/50°C)(NCP15WF104F03RC made by MURATA MANUFACTURING).
- * When the battery overdischarge condition, it fast charge current (IFSTCHG2)×1/10 mA charge for 149.5 seconds, and then it does not switch to pre-charging during that interval, it means the IC has identified a battery abnormality.
- * If adjacent terminals are shorted or each terminal is short with V_{DD} or GND, there is a possibility that the IC malfunctions.

Measuring Circuit



Timing Chart

Case of normal charging

VDD,ON VDD control voltage VDD control voltage 4.2V Vdd 0V BAT output voltage Output voltage 4.2V BAT pin - 3.9V voltage -2.9V Pre charge detection Re-charge Pre charge detection -2.0V detection Full charge Charging current 0A _ _ _ _ Pre charge Fast charging LED-R ON OFF ON LED-G OFF ON OFF

Case of connecting abnormal adapter



Case of setting battery error (temparature detection pin ; open)



Case of overcharged battery





Case of time-up for Pre charging



Case of time-up for full charging



Case of Full charged battery



Case of Re-charged battery



Flow Chart



Application Circuit



- These circuits are typical examples provided for reference purposes, so in actual applications, the circuit constants, conditions and operations should be thoroughly studied.
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- \cdot If terminal CNT(4pin) is short with V_DD, V_DD voltage keeps rising, and becoming it at risk.
- So in actual applications, the circuit constants, conditions and operations should be thoroughly studied.